

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

	Havemann et al.	Examiner: TBD
Serial No:	TBD	Art Unit: TBD
Filed:	11/01/01	Docket No.: TI-27506
For:	INTEGRATED CIRCUIT HAVING A DOPED POROUS DIELECTRIC AND METHOD OF MANUFACTURING THE SAME	

PRELIMINARY AMENDMENT

November 1, 2001

Assistant Commissioner for Patents

Washington, DC 20231

Dear Sir:

Please amend the above referenced application as follows:

In the Specification:

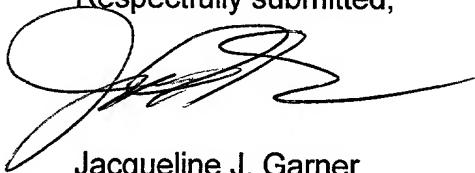
Page 1, before line 1, insert --This application claims priority under 35 USC § 119(e)(1) of provisional application numbers 60/251,494 filed 12/05/00.--

REMARKS

Entry of the foregoing amendment prior to examination is respectfully requested.

If the Examiner has any questions or other correspondence regarding this application, Applicant requests that the Examiner contact Applicant's attorney at the below listed telephone number and address.

Respectfully submitted,



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